

Flexible metal-oxide devices made by room-temperature sol-gel films

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Citation Report

#	ARTICLE	IF	CITATIONS
3	Photobias Instability of High Performance Solution Processed Amorphous Zinc Tin Oxide Transistors. ACS Applied Materials & Interfaces, 2013, 5, 3255-3261.	8.0	61
4	Metal salt-derived InGaZnO semiconductors incorporating formamide as a novel co-solvent for producing solution-processed, electrohydrodynamic-jet printed, high performance oxide transistors. Journal of Materials Chemistry C, 2013, 1, 4236.	5.5	73
5	29.4: <i>Invited Paper</i>: Paper Electronics: A Challenge for the Future. Digest of Technical Papers SID International Symposium, 2013, 44, 365-367.	0.3	4
7	Bonding and Structure of Ceramic-Ceramic Interfaces. Physical Review Letters, 2013, 111, 066103.	7.8	16
8	Co3O4 nanocrystals with predominantly exposed facets: synthesis, environmental and energy applications. Journal of Materials Chemistry A, 2013, 1, 14427.	10.3	147
9	Functionalized ZnO nanoparticles for thin-film transistors: support of ligand removal by non-thermal methods. Journal of Materials Chemistry C, 2013, 1, 3098.	5.5	24
10	High-performance low-voltage organic transistor memories with room-temperature solution-processed hybrid nanolayer dielectrics. Journal of Materials Chemistry C, 2013, 1, 3291.	5.5	29
11	Graphene electrodes transfer-printed with a surface energy-mediated wet PDMS stamp: impact of Au doped-graphene for high performance soluble oxide thin-film transistors. Journal of Materials Chemistry C, 2013, 1, 5632.	5.5	15
12	Tunable near-infrared and visible-light transmittance in nanocrystal-in-glass composites. Nature, 2013, 500, 323-326.	27.8	742
13	Room temperature photo-induced, Eu3+-doped IGZO transparent thin films fabricated using sol-gel method. Journal of Nanostructure in Chemistry, 2013, 3, 1.	9.1	5
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18	Mechanisms of Zinc Oxide Nanocrystalline Thin Film Formation by Thermal Degradation of Metal-Loaded Hydrogels. Journal of Physical Chemistry C, 2013, 117, 25108-25117.	3.1	11
19	The Effect of Metal Composition on Bias Stability of Solution Processed Indium Oxide Based Thin Film Transistors. ECS Journal of Solid State Science and Technology, 2013, 2, Q200-Q204.	1.8	10
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23	In/Ga-Free, Inkjet-Printed Charge Transfer Doping for Solution-Processed ZnO. <i>ACS Applied Materials & Interfaces</i> , 2013, 5, 9765-9769.	8.0	33
24	Flexible organic/inorganic heterojunction transistors with low operating voltage. <i>Journal of Materials Chemistry C</i> , 2013, 1, 7073.	5.5	14
25	Impact of UV/O ₃ treatment on solution-processed amorphous InGaZnO ₄ thin-film transistors. <i>Journal of Applied Physics</i> , 2013, 113, .	2.5	68
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965	Low–Temperature, Universal Synthetic Route for Mesoporous Metal Oxides by Exploiting Synergistic Effect of Thermal Activation and Plasma. Advanced Materials, 2024, 36, .	21.0	0
966	Self-Assembled Monolayers of Push–Pull Chromophores as Active Layers and Their Applications. Molecules, 2024, 29, 559.	3.8	0
967	Large Size and High Resolution Organic Light Emitting Diodes Based on the In-Ga-Zn-O Thin Film Transistors with a Coplanar Structure. Korean Journal of Materials Research, 2023, 33, 511-516.	0.2	0
968	Light Effect on Amorphous Tin Oxide Thin–Film Transistors. Advanced Photonics Research, 2024, 5, .	3.6	0
969	Synthesis of Silicon and Germanium Oxide Nanostructures via Photonic Curing; a Facile Approach to Scale Up Fabrication. ChemistryOpen, 0, , .	1.9	0
970	Developing flexible QLEDs using metal oxide and polymer combination. Optical Materials, 2024, 149, 115041.	3.6	0
971	Dual External Electron Injection Barrier Layers Enable High–Performance Near–Infrared Organic Photodetectors Realizing Real–Time Heart Rate Monitoring. Advanced Optical Materials, 0, , .	7.3	0
972	Dependence of Positive Bias Stress Instability on Threshold Voltage and Its Origin in Solution-Processed Aluminum-Doped Indium Oxide Thin-Film Transistors. Nanomaterials, 2024, 14, 466.	4.1	0
973	Solution–Processed Metal Oxide Thin–Film Transistor at Low Temperature via A Combination Strategy of $H_{2}O_{2}$ –Inducement Technique and Infrared Irradiation Annealing. Small Methods, 0, , .	8.6	0
974	High–Performance Nd: AlZO/Al ₂ O ₃ Dual Active Layer Design Without Thermal Annealing: High–Speed Electron Transport and Defect Modification in Thin Film Transistors. Advanced Engineering Materials, 2024, 26, .	3.5	0
975	High-Quality TiO ₂ Electron Transport Film Prepared via Vacuum Ultraviolet Illumination for MAPbI ₃ Perovskite Solar Cells. Inorganic Chemistry, 2024, 63, 5709-5717.	4.0	0